



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Christine Hau-Riege, et al.

Group Art Unit: 2823

Application No.: 10/697,214

Examiner: William M. Brewster

Filed: October 29, 2003

Title: SEMICONDUCTOR COMPONENT AND METHOD FOR PRECLUDING
STRESS-INDUCED VOID FORMATION IN THE SEMICONDUCTOR
COMPONENT

AMENDMENT UNDER 37 C.F.R. § 1.312

Mail Stop Issue Fee
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Madam/Sir:

In response to the Notice of Allowance and Issue Fee Due mailed April 7, 2005,
please amend the application as follows:

OK to enter
William M. Brewster
21 JUL 05